

## Electronic Acknowledgement Receipt

<b>EFS ID:</b>	8353578
<b>Application Number:</b>	10565621
<b>International Application Number:</b>	
<b>Confirmation Number:</b>	2319
<b>Title of Invention:</b>	Stacked structure and production method thereof
<b>First Named Inventor/Applicant Name:</b>	Hubert Moriceau
<b>Customer Number:</b>	90678
<b>Filer:</b>	Jasper W. Dockrey
<b>Filer Authorized By:</b>	
<b>Attorney Docket Number:</b>	9905-37 (BIF116044/US)
<b>Receipt Date:</b>	03-SEP-2010
<b>Filing Date:</b>	25-JUL-2006
<b>Time Stamp:</b>	17:05:42
<b>Application Type:</b>	U.S. National Stage under 35 USC 371

### Payment information:

Submitted with Payment	no
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### File Listing:

Document Number	Document Description	File Name	File Size(Bytes)/ Message Digest	Multi Part /.zip	Pages (if appl.)
1	NPL Documents	15-NF-OA-10-05-05.pdf	283265 dd315ac98b43f6c051370ecb57a23c0e27e1d7fe	no	8

### Warnings:

### Information:

2	NPL Documents	15-F-OA-05-03-06.pdf	400743	no	11
			72d5f0d1b05a1ed2bdefc93e9557dca3992f7ecc		
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3	NPL Documents	15-NF-OA-01-10-07.pdf	457128	no	12
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5	NPL Documents	15-NF-OA-02-11-08.pdf	407731	no	11
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6	NPL Documents	15-F-OA-10-29-08.pdf	416204	no	11
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7	NPL Documents	15-NF-OA-6-25-09.pdf	273969	no	8
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8	NPL Documents	16-OA-NF-9-24-04_1.PDF	271574	no	7
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23	NPL Documents	Ono_et_al_Orientation_Dependence_of_Flaking_of_Ion_Irradiated.pdf	349210	no	6
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24	NPL Documents	Paszti_E-Flaking_and_Wave-Like_Structure_On_Metallic_Glasses_Induced_By_MeV-Energy_Helium_Ions.pdf	811448	no	8
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26	NPL Documents	Pollentier_et_al-Fabrication_of_High-Radiance_LEDs_by_Epitaxial_Lift-Off.pdf	849591	no	7
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28	NPL Documents	Primak_W-Impurity_Effect_In_the_Ionization_Dilation_of_Vitreous_Silica.pdf	792830	no	8
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32	NPL Documents	Sah_Chih-Tang_et_al-Deactivation_of_the_Boron_Acceptor_in_Silicon_by_Hydrogen.pdf	300754	no	3
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47	NPL Documents	Theodore_N_David_et_al-TFSOI_With_Improved_Oxidation_Resistance.pdf	208814 c2be987cd9f9ecf71b113c48b15f74735cc0b5e7	no	2
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53	NPL Documents	Van_de_Walle_C_et_al-Theory_of_Hydrogen-Vol-60.pdf	285435 e3d755933463ad757a8b4163c55d97bca8005575	no	3
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59	NPL Documents	Venezia-VC-The-Role-Of-Implantation-Damage.PDF	539126 7c9ec387070ba1be66e169d4dfa86067ea221e9d	no	6
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Total Files Size (in bytes):			35385648		
<p>This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.</p> <p><b><u>New Applications Under 35 U.S.C. 111</u></b> If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.</p> <p><b><u>National Stage of an International Application under 35 U.S.C. 371</u></b> If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.</p> <p><b><u>New International Application Filed with the USPTO as a Receiving Office</u></b> If a new international application is being filed and the international application includes the necessary components for an international filing date (see PCT Article 11 and MPEP 1810), a Notification of the International Application Number and of the International Filing Date (Form PCT/RO/105) will be issued in due course, subject to prescriptions concerning national security, and the date shown on this Acknowledgement Receipt will establish the international filing date of the application.</p>					